Unit: mm

TOSHIBA Transistor Silicon NPN Triple Diffused Type

2SC4688

Power Amplifier Applications

- Complementary to 2SA1803
- Suitable for use in 40-W high fidelity audio amplifier's output stage

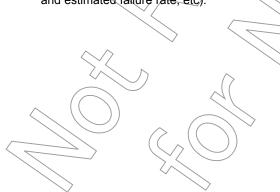
Absolute Maximum Ratings (Tc = 25°C)

Characteristics		Rating	Unit	
Collector-base voltage		80	V	
Collector-emitter voltage		80	$(\mathcal{N} \land)$	
Emitter-base voltage		5	V	
DC	IC	6	A	
Pulse	I _{CP}	12		
Base current		0.6	Α	
Collector power dissipation		55	W	
(Tc = 25°C)		35	VV	
Junction temperature		150	<⟨c	
Storage temperature range		-55 to 150	°¢/	
	DC Pulse on	VCBO VCEO VEBO DC IC Pulse ICP IB On PC Tj	VCBO 80 VCEO 80 VEBO 5 DC IC 6 Pulse ICP 12 IB 0.6 on PC 55	

Weight: 5.8 g (typ.)

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliab

temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

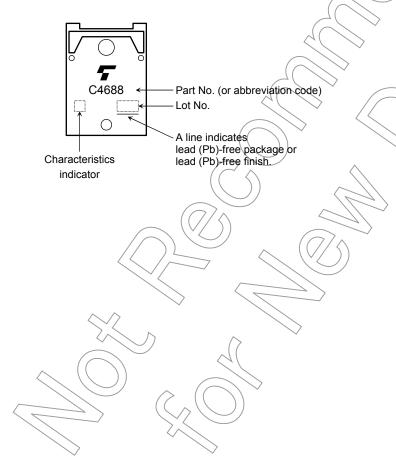


Electrical Characteristics (Tc = 25°C)

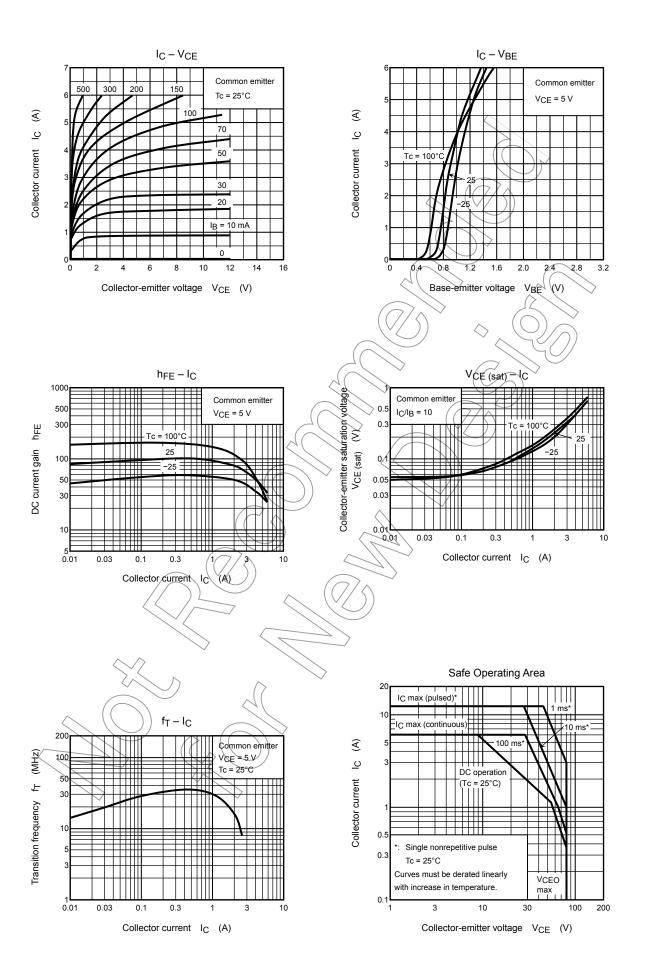
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	I _{CBO}	V _{CB} = 80 V, I _E = 0	_	_	5.0	μΑ
Emitter cut-off current	I _{EBO}	V _{EB} = 5 V, I _C = 0	_	_	5.0	μΑ
Collector-emitter breakdown voltage	V (BR) CEO	I _C = 50 mA, I _B = 0	80	_	_	V
DC current gain	h _{FE (1)} (Note)	V _{CE} = 5 V, I _C = 1 A	55) }	160	
	h _{FE (2)}	V _{CE} = 5 V, I _C = 3 A	35	75	-	
Collector-emitter saturation voltage	V _{CE} (sat)	I _C = 5 A, I _B = 0.5 A	\rightarrow	0.45	2.0	٧
Base-emitter voltage	V _{BE}	V _{CE} = 5 V, I _C = 3 A	_	0.92	1.5	V
Transition frequency	f _T	V _{CE} = 5 V, I _C = 1 A	_	30	_	MHz
Collector output capacitance	C _{ob}	V _{CB} = 10 V, I _E = 0, f = 1 MHz	_	105	_	pF

Note: $h_{FE(1)}$ classification R: 55 to 110, O: 80 to 160

Marking



2 2006-11-10





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20070701-EN

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